One-dimensional PSD **\$8673**

One-dimensional PSD using SIP (Single Inline Package)

ackage)

S8673 is a one-dimensional PSD with a 1.0 × 3.0 mm active area, molded into a SIP (Single Inline Package).

Features

- Thin, miniature plastic package (SIP style)
- Active area: 1.0 × 3.0 mm (resistance length 3.0 mm)

Applications

- Optical switches
- Displacement meters

■ Absolute maximum ratings (Ta=25 °C)

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Parameter	Symbol	Value	Unit			
Reverse voltage	VR Max.	20	V			
Operating temperature	Topr	-25 to +85	°C			
Storage temperature	Tstg	-40 to +100	°C			

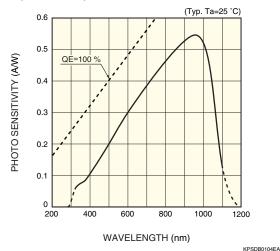
■ Electrical and optical characteristics (Ta=25 °C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Spectral response range	λ		-	320 to 1100	-	nm
Peak sensitivity wavelength	λр		-	960	•	nm
Photo sensitivity	S	λ=890 nm	-	0.5	ı	A/W
Position detection error	-	Vr=1 V, *	-	±10	±30	μm
Interelectrode resistance	Rie	Vb=0.1 V	100	140	180	kΩ
Dark current	ΙD	Vr=1 V	-	0.05	1	nA
Temperature coefficient of ID	TCID		-	1.15	-	times/°C
Rise time	tr	VR=1 V, RL=1 kΩ λ =650 nm	-	3	-	μs
Terminal capacitance	Ct	VR=1 V, f=10 kHz	-	15	30	pF
Saturation photocurrent	Ist	VR=1 V, RL=1 kΩ	30	-	-	μΑ

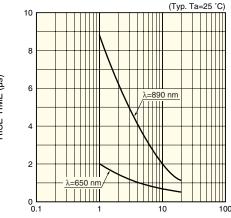
^{*} In the range 75 % from the center of the active area to the edge.



■ Spectral response



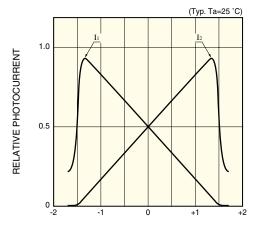
RISE TIME (µs)



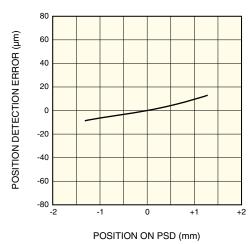
REVERSE VOLTAGE (V)

KPSDB0105EA

■ Position detection characteristic example



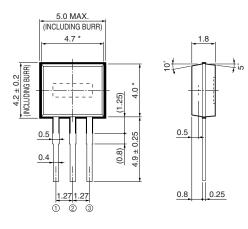
POSITION ON PSD (mm)

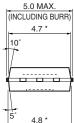


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■ Dimensional outline (unit: mm)

■ Rise time vs. reverse voltage





- ① ANODE 1
- ② CATHODE (COMMON)
- 3 ANODE 2

Tolerance unless otherwise noted: ± 0.1 , $\pm 2^{\circ}$ Shaded area indicates burr. Chip position accuracy with respect to the package dimensions marked * X, Y $\leq \pm 0.2$, $\theta \leq \pm 2^{\circ}$

KPSDA0061EA

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